Substitute for Form 1449 A & B/PTO

Sheet

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

of

Comp	Complete if Known						
Application Number	Divisional of 08/866,331(10/674						
Confirmation Number	Not yet assigned						
Filing Date	October 1, 2003						
First Named Inventor	Hiroshi TANABE						
Art Unit	2822 (Parent)						
Examiner Name	Not yet assigned						
Attorney Docket Number	Q77312						

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Examiner Initials*	Cite No.1	Document Num Number	nber Kind Code²	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
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Initials*	No.1	Country Code ³	Number ⁴	Kind Code ⁵ (if known)	MM-DD-YYYY	Applicant of Cited Document	Translation*		
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Examiner Initials*	Cite No. ¹		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, ournal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.									
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Substitute for Form 14	INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)	_	Complete if Known			
Substitute for Ports 14	49 A & B/F10			Application Number	Divisional of 08/866,331 (10/674)	
INFO	RMATION	DISCLOS	SURE	Confirmation Number	Not yet assigned	
STAT	EMENT BY	Y APPLIC	CANT	Filing Date	October 1, 2003	
2				First Named Inventor	Hiroshi TANABE	
(us	e as many sheel	is as necessa	ry)	Art Unit	2822 (Parent)	
				Examiner Name	Not yet assigned	
Sheet	Sheet 2 of 3		2	Attorney Docket Number	Q77312	

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